

MDL-III-975L/1~200mW



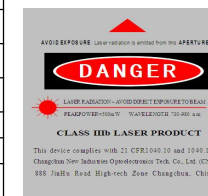
INFRARED DIODE LASER AT 975nm

It features ultra compact design, long lifetime, cost-effectiveness and easy operation. They are used in measurement, communication, spectrum analysis, etc.



SPECIFICATIONS

Central wavelength (nm)	975±10
Operating mode	CW
Output power (mW)	>1, 10, 20, ..., 200
Power stability (rms, over 4 hours)	<3%, <2%, <1%, <0.5%
Transverse mode	Near TEM ₀₀
M ² factor	~1.5 (~1.2, optional)
Beam diameter at the aperture ((1/e ² ,mm)	~3.5 (~1.2, optional)
Beam divergence, full angle (mrad)	<1.0
Warm-up time (minutes)	<5
Beam height from base plate (mm)	24. 8
Operating temperature (°C)	10~35
Power supply	85-264VAC PSU-III-LED/ PSU-III-FDA (Frequency for 1Hz-30kHz) 100-240VAC PSU-A-D (Frequency for 30kHz -100kHz)
Modulation optional	TTL on/off, 1Hz-1kHz, 1kHz-10kHz, 10kHz-30kHz, 30kHz-100kHz; and Analog modulation optional
Expected lifetime (hours)	10000
Warranty	1 year



MDL-III-975L	PSU-III-LED	PSU-III-FDA	PSU-A-D
143.5(L)×73(W)×46.2(H) mm³, 0.7kg	188.6 (L)×155(W)×92 (H) mm³, 1.5kg	171(L)×130(W)×62.2 (H) mm³, 1.2kg	162(L)×144(W)×70 (H) mm³, 1.0kg